1 Features
- Inverts or Doubles Input Supply Voltage
- 3.5-Ω Typical Output Resistance
- 86% Typical Conversion Efficiency at 200 mA
- (LM2662) Selectable Oscillator Frequency: 20 kHz/150 kHz
- (LM2663) Low Current Shutdown Mode

2 Applications
- Laptop Computers
- Cellular Phones
- Medical Instruments
- Operational Amplifier Power Supplies
- Interface Power Supplies
- Handheld Instruments

3 Description
The LM2662/LM2663 CMOS charge-pump voltage converter inverts a positive voltage in the range of 1.5 V to 5.5 V to the corresponding negative voltage. The LM2662/LM2663 uses two low cost capacitors to provide 200 mA of output current without the cost, size, and EMI related to inductor based converters. With an operating current of only 300 μA and operating efficiency greater than 90% at most loads, the LM2662/LM2663 provides ideal performance for battery powered systems. The LM2662/LM2663 may also be used as a positive voltage doubler.

The oscillator frequency can be lowered by adding an external capacitor to the OSC pin. Also, the OSC pin may be used to drive the LM2662/LM2663 with an external clock. For LM2662, a frequency control (FC) pin selects the oscillator frequency of 20 kHz or 150 kHz. For LM2663, an external shutdown (SD) pin replaces the FC pin. The SD pin can be used to disable the device and reduce the quiescent current to 10 μA. The oscillator frequency for LM2663 is 150 kHz.

Device Information

<table>
<thead>
<tr>
<th>PART NUMBER</th>
<th>PACKAGE</th>
<th>BODY SIZE (NOM)</th>
</tr>
</thead>
<tbody>
<tr>
<td>LM2662</td>
<td>SOIC (8)</td>
<td>4.90 mm x 3.91 mm</td>
</tr>
<tr>
<td>LM2663</td>
<td>SOIC (8)</td>
<td>4.90 mm x 3.91 mm</td>
</tr>
</tbody>
</table>

(1) For all available packages, see the orderable addendum at the end of the datasheet.

*Please see Positive Voltage Doubler section regarding choice of D1.*
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4 Revision History
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision D (May 2013) to Revision E  Page
• Added Device Information and Handling Rating tables, Feature Description, Device Functional Modes, Application and Implementation, Power Supply Recommendations, Layout, Device and Documentation Support, and Mechanical, Packaging, and Orderable Information sections; moved some curves to Application Curves section .............. 1

Changes from Revision C (May 2013) to Revision D  Page
• Changed layout of National Data Sheet to TI format ................................................................. 15
5 Pin Configuration and Functions

![8 Pins LM2662 SOIC (D) Top View](image1)

### Pin Functions

<table>
<thead>
<tr>
<th>PIN</th>
<th>DESCRIPTION</th>
</tr>
</thead>
<tbody>
<tr>
<td><strong>VOLTAGE INVERTER</strong></td>
<td><strong>VOLTAGE DOUBLER</strong></td>
</tr>
<tr>
<td><strong>TYPE</strong></td>
<td><strong>NAME</strong></td>
</tr>
<tr>
<td>FC (LM2662)</td>
<td>Input</td>
</tr>
<tr>
<td>SD (LM2663)</td>
<td>Input</td>
</tr>
<tr>
<td>CAP+</td>
<td>Power</td>
</tr>
<tr>
<td>GND</td>
<td>Ground</td>
</tr>
<tr>
<td>CAP−</td>
<td>Power</td>
</tr>
<tr>
<td>OUT</td>
<td>Power</td>
</tr>
<tr>
<td>LV</td>
<td>Input</td>
</tr>
<tr>
<td>OSC</td>
<td>Input</td>
</tr>
<tr>
<td>V+</td>
<td>Power Input</td>
</tr>
</tbody>
</table>
6 Specifications

6.1 Absolute Maximum Ratings

<table>
<thead>
<tr>
<th>MIN</th>
<th>MAX</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>Supply voltage (V+ to GND, or GND to OUT)</td>
<td>6</td>
<td>V</td>
</tr>
<tr>
<td>LV (OUT − 0.3 V)</td>
<td>(GND + 3 V)</td>
<td></td>
</tr>
<tr>
<td>FC, OSC, SD</td>
<td>The least negative of (OUT − 0.3 V) or (V+ − 6 V) to (V+ + 0.3 V)</td>
<td></td>
</tr>
<tr>
<td>V+ and OUT continuous output current</td>
<td>250</td>
<td>sec.</td>
</tr>
<tr>
<td>Output short-circuit duration to GND</td>
<td>1</td>
<td>sec.</td>
</tr>
<tr>
<td>Power dissipation (T_A = 25°C)</td>
<td>735</td>
<td>mW</td>
</tr>
<tr>
<td>T_J max</td>
<td>150</td>
<td>°C</td>
</tr>
<tr>
<td>Operating ambient temperature</td>
<td>−40</td>
<td>85</td>
</tr>
<tr>
<td>Operating junction temperature</td>
<td>−40</td>
<td>105</td>
</tr>
<tr>
<td>Lead temperature (soldering, 10 seconds)</td>
<td>300</td>
<td></td>
</tr>
</tbody>
</table>

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/Distributors for availability and specifications.

(3) OUT may be shorted to GND for one second without damage. However, shorting OUT to V+ may damage the device and should be avoided. Also, for temperatures above 85°C, OUT must not be shorted to GND or V+, or device may be damaged.

(4) The maximum allowable power dissipation is calculated by using \( P_{D,\text{Max}} = \frac{(T_{J,\text{Max}} - T_A)}{R_{\theta,JA}} \), where \( T_{J,\text{Max}} \) is the maximum junction temperature, \( T_A \) is the ambient temperature, and \( R_{\theta,JA} \) is the junction-to-ambient thermal resistance of the specified package.

6.2 Handling Ratings

<table>
<thead>
<tr>
<th>MIN</th>
<th>MAX</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>Storage temperature range</td>
<td>−65</td>
<td>150</td>
</tr>
<tr>
<td>Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins</td>
<td>2000</td>
<td>V</td>
</tr>
</tbody>
</table>

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

<table>
<thead>
<tr>
<th>MIN</th>
<th>NOM</th>
<th>MAX</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>V+ (supply voltage)</td>
<td>2.5</td>
<td>5.5</td>
<td>V</td>
</tr>
<tr>
<td>Junction temperature (T_J)</td>
<td>−40</td>
<td>105</td>
<td>°C</td>
</tr>
<tr>
<td>Ambient temperature (T_A)</td>
<td>−40</td>
<td>85</td>
<td></td>
</tr>
</tbody>
</table>

6.4 Thermal Information

<table>
<thead>
<tr>
<th>LM2662</th>
<th>LM2663</th>
</tr>
</thead>
<tbody>
<tr>
<td>SOIC (D)</td>
<td>8 PINS</td>
</tr>
<tr>
<td>R_{\theta,JA}</td>
<td>Junction-to-ambient thermal resistance</td>
</tr>
<tr>
<td>170</td>
<td>170</td>
</tr>
</tbody>
</table>

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.
### 6.5 Electrical Characteristics

Unless otherwise specified: \( V^+ = 5 \text{ V}, FC = \text{Open}, C_1 = C_2 = 47 \mu\text{F}. \)

<table>
<thead>
<tr>
<th>PARAMETER</th>
<th>TEST CONDITION</th>
<th>( \text{MIN}^{(2)} )</th>
<th>( \text{TYP}^{(3)} )</th>
<th>( \text{MAX}^{(2)} )</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>( V^+ ) Supply Voltage</td>
<td>( R_L = 1k )</td>
<td></td>
<td>3.5</td>
<td>5.5</td>
<td>\text{V}</td>
</tr>
<tr>
<td></td>
<td>Inverter, ( \text{LV} = \text{Open} )</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td>Inverter, ( \text{LV} = \text{GND} )</td>
<td></td>
<td>1.5</td>
<td>5.5</td>
<td></td>
</tr>
<tr>
<td></td>
<td>Doubler, ( \text{LV} = \text{OUT} )</td>
<td></td>
<td>2.5</td>
<td>5.5</td>
<td></td>
</tr>
<tr>
<td>( I_O ) Supply Current</td>
<td>No Load</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td>( \text{LV} = \text{Open} )</td>
<td></td>
<td>1.3</td>
<td>4</td>
<td>\text{mA}</td>
</tr>
<tr>
<td></td>
<td>FC = ( V^+ ) (LM2662)</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td>SD = \text{Ground} (LM2663)</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td>FC = \text{Open}</td>
<td></td>
<td>0.3</td>
<td>0.8</td>
<td></td>
</tr>
<tr>
<td>( I_{SD} ) Shutdown Supply Current (LM2663)</td>
<td></td>
<td></td>
<td>10</td>
<td>10</td>
<td>\text{mA}</td>
</tr>
<tr>
<td>( V_{SD} ) Shutdown Pin Input Voltage (LM2663)</td>
<td>Shutdown Mode</td>
<td></td>
<td>2</td>
<td></td>
<td>\text{V}</td>
</tr>
<tr>
<td></td>
<td>Normal Operation</td>
<td></td>
<td>0.3</td>
<td></td>
<td></td>
</tr>
<tr>
<td>( I_L ) Output Current</td>
<td>( I_L = 200 \text{ mA} )</td>
<td></td>
<td>3.5</td>
<td>7</td>
<td>\text{mA}</td>
</tr>
<tr>
<td>( R_{OUT} ) Output Resistance (^{(5)})</td>
<td>( I_L = 200 \text{ mA} )</td>
<td></td>
<td>7</td>
<td>20</td>
<td>\text{kHz}</td>
</tr>
<tr>
<td>( f_{OSC} ) Oscillator Frequency (^{(6)})</td>
<td>OSC = \text{Open}</td>
<td></td>
<td>55</td>
<td>150</td>
<td>\text{kHz}</td>
</tr>
<tr>
<td></td>
<td>FC = \text{Open}</td>
<td></td>
<td>3.5</td>
<td>10</td>
<td></td>
</tr>
<tr>
<td></td>
<td>FC = ( \text{V}^+ )</td>
<td></td>
<td>27.5</td>
<td>75</td>
<td></td>
</tr>
<tr>
<td>( f_{SW} ) Switching Frequency (^{(7)})</td>
<td>OSC = \text{Open}</td>
<td></td>
<td>±2</td>
<td></td>
<td>\text{µA}</td>
</tr>
<tr>
<td></td>
<td>FC = \text{Open}</td>
<td></td>
<td>±10</td>
<td></td>
<td></td>
</tr>
<tr>
<td>( I_{OSC} ) OSC Input Current</td>
<td>FC = \text{Open}</td>
<td></td>
<td>±2</td>
<td></td>
<td>\text{µA}</td>
</tr>
<tr>
<td></td>
<td>FC = ( \text{V}^+ )</td>
<td></td>
<td>±10</td>
<td></td>
<td></td>
</tr>
<tr>
<td>( P_{EFF} ) Power Efficiency</td>
<td>( R_L (500) ) between ( \text{V}^+ ) and ( \text{OUT} )</td>
<td></td>
<td>90%</td>
<td>96%</td>
<td></td>
</tr>
<tr>
<td></td>
<td>( I_L = 200 \text{ mA to GND} )</td>
<td></td>
<td>86%</td>
<td></td>
<td></td>
</tr>
<tr>
<td>( V_{OEFF} ) Voltage Conversion Efficiency</td>
<td>No Load</td>
<td></td>
<td>99%</td>
<td>99.96%</td>
<td></td>
</tr>
</tbody>
</table>

(1) In the test circuit, capacitors \( C_1 \) and \( C_2 \) are 47-\( \mu \text{F}, 0.2-\Omega \) maximum ESR capacitors. Capacitors with higher ESR will increase output resistance, reduce output voltage and efficiency.

(2) –40°C to 105°C

(3) \( T_J = 25°C \)

(4) In doubling mode, when \( \text{V}_{\text{out}} > 5 \text{ V} \), minimum input high for shutdown equals \( \text{V}_{\text{out}} - 3 \text{ V} \).

(5) Specified output resistance includes internal switch resistance and capacitor ESR.

(6) For LM2663, the oscillator frequency is 150 kHz.

(7) The output switches operate at one half of the oscillator frequency, \( f_{\text{OSC}} = 2f_{\text{SW}} \).
6.6 Typical Performance Characteristics
(Circuit of Figure 14 and Figure 15)

Figure 1. Supply Current vs Supply Voltage

Figure 2. Supply Current vs Oscillator Frequency

Figure 3. Output Source Resistance vs Supply Voltage

Figure 4. Output Source Resistance vs Temperature

Figure 5. Output Source Resistance vs Temperature

Figure 6. Output Voltage Drop vs Load Current

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Product Folder Links: LM2662  LM2663
Typical Performance Characteristics (continued)

(Circuit of Figure 14 and Figure 15)

![Figure 7. Output Voltage vs Oscillator Frequency](image1)

![Figure 8. Oscillator Frequency vs External Capacitance](image2)

![Figure 9. Oscillator Frequency vs Supply Voltage](image3)

![Figure 10. Oscillator Frequency vs Supply Voltage](image4)

![Figure 11. Oscillator Frequency vs Temperature](image5)

![Figure 12. Oscillator Frequency vs Temperature](image6)
Typical Performance Characteristics (continued)

(Circuit of Figure 14 and Figure 15)

Figure 13. Shutdown Supply Current vs Temperature (LM2663 Only)
7 Parameter Measurement Information

* Figure 14. LM2662 Test Circuit

* Figure 15. LM2663 Test Circuit
8 Detailed Description

8.1 Overview

The LM2662/LM2663 contains four large CMOS switches which are switched in a sequence to invert the input supply voltage. Energy transfer and storage are provided by external capacitors. Figure 16 illustrates the voltage conversion scheme. When $S_1$ and $S_3$ are closed, $C_1$ charges to the supply voltage $V^+$. During this time interval switches $S_2$ and $S_4$ are open. In the second time interval, $S_1$ and $S_3$ are open and $S_2$ and $S_4$ are closed, $C_1$ is charging $C_2$. After a number of cycles, the voltage across $C_2$ will be pumped to $V^+$. Since the anode of $C_2$ is connected to ground, the output at the cathode of $C_2$ equals $-(V^+)$ assuming no load on $C_2$, no loss in the switches, and no ESR in the capacitors. In reality, the charge transfer efficiency depends on the switching frequency, the on-resistance of the switches, and the ESR of the capacitors.

Figure 16. Voltage Inverting Principle

8.2 Functional Block Diagram

8.3 Feature Description

8.3.1 Changing Oscillator Frequency

For the LM2662, the internal oscillator frequency can be selected using the Frequency Control (FC) pin. When FC is open, the oscillator frequency is 20 kHz; when FC is connected to $V^+$, the frequency increases to 150 kHz. A higher oscillator frequency allows smaller capacitors to be used for equivalent output resistance and ripple, but increases the typical supply current from 0.3 mA to 1.3 mA.

The oscillator frequency can be lowered by adding an external capacitor between OSC and GND (See typical performance characteristics). Also, in the inverter mode, an external clock that swings within 100 mV of $V^+$ and GND can be used to drive OSC. Any CMOS logic gate is suitable for driving OSC. LV must be grounded when driving OSC. The maximum external clock frequency is limited to 150 kHz.

The switching frequency of the converter (also called the charge pump frequency) is half of the oscillator frequency.

NOTE

OSC cannot be driven by an external clock in the voltage-doubling mode.
Feature Description (continued)

Table 1. LM2662 Oscillator Frequency Selection

<table>
<thead>
<tr>
<th>FC</th>
<th>OSC</th>
<th>OSCILLATOR</th>
</tr>
</thead>
<tbody>
<tr>
<td>Open</td>
<td>Open</td>
<td>20 kHz</td>
</tr>
<tr>
<td>V+</td>
<td>Open</td>
<td>150 kHz</td>
</tr>
<tr>
<td>Open or V+</td>
<td>External Capacitor</td>
<td>See Typical Performance Characteristics</td>
</tr>
<tr>
<td>N/A</td>
<td>External Clock (inverter mode only)</td>
<td>External Clock Frequency</td>
</tr>
</tbody>
</table>

Table 2. LM2663 Oscillator Frequency Selection

<table>
<thead>
<tr>
<th>OSC</th>
<th>OSCILLATOR</th>
</tr>
</thead>
<tbody>
<tr>
<td>Open</td>
<td>150 kHz</td>
</tr>
<tr>
<td>External Capacitor</td>
<td>See Typical Performance Characteristics</td>
</tr>
<tr>
<td>External Clock (inverter mode only)</td>
<td>External Clock Frequency</td>
</tr>
</tbody>
</table>

8.4 Device Functional Modes

8.4.1 Shutdown Mode

For the LM2663, a shutdown (SD) pin is available to disable the device and reduce the quiescent current to 10 μA. Applying a voltage greater than 2 V to the SD pin will bring the device into shutdown mode. While in normal operating mode, the SD pin is connected to ground.
9 Application and Implementation

NOTE
Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information
The LM2662/LM2663 CMOS charge-pump voltage converter inverts a positive voltage in the range of 1.5 V to 5.5 V to the corresponding negative voltage. The LM2662/LM2663 uses two low cost capacitors to provide 200 mA of output current without the cost, size, and EMI related to inductor based converters. With an operating current of only 300 μA and operating efficiency greater than 90% at most loads, the LM2662/LM2663 provides ideal performance for battery powered systems. The LM2662/LM2663 may also be used as a positive voltage doubler.

9.2 Typical Applications
9.2.1 Simple Negative Voltage Converter

9.2.1.1 Design Requirements
The main application of LM2662/LM2663 is to generate a negative supply voltage. The voltage inverter circuit uses only two external capacitors as shown in Figure 17. The range of the input supply voltage is 1.5 V to 5.5 V. For a supply voltage less than 3.5 V, the LV pin must be connected to ground to bypass the internal regulator circuitry. This gives the best performance in low voltage applications. If the supply voltage is greater than 3.5 V, LV may be connected to ground or left open. The choice of leaving LV open simplifies the direct substitution of the LM2662/LM2663 for the LMC7660 Switched Capacitor Voltage Converter.

9.2.1.2 Detailed Design Procedure
The output characteristics of this circuit can be approximated by an ideal voltage source in series with a resistor. The voltage source equals \(-V_+\). The output resistance \(R_{\text{out}}\) is a function of the ON resistance of the internal MOS switches, the oscillator frequency, and the capacitance and ESR of \(C_1\) and \(C_2\). Since the switching current charging and discharging \(C_1\) is approximately twice as the output current, the effect of the ESR of the pumping capacitor \(C_1\) is multiplied by four in the output resistance. The output capacitor \(C_2\) is charging and discharging at a current approximately equal to the output current, therefore, its ESR only counts once in the output resistance. A good approximation is:

\[
R_{\text{out}} \approx 2R_{\text{SW}} + \frac{2}{f_{\text{osc}} \times C_1} + 4 \text{ESR}_{C_1} + \text{ESR}_{C_2}
\]

(1)

where \(R_{\text{SW}}\) is the sum of the ON resistance of the internal MOS switches shown in the Voltage Inverting Principle.

High value, low ESR capacitors will reduce the output resistance. Instead of increasing the capacitance, the oscillator frequency can be increased to reduce the \(2/(f_{\text{osc}} \times C_1)\) term. Once this term is trivial compared with \(R_{\text{SW}}\) and ESRs, further increasing in oscillator frequency and capacitance will become ineffective.

Figure 17. Simple Negative Voltage Converter

9.2.2 Detailed Design Procedure
The output characteristics of this circuit can be approximated by an ideal voltage source in series with a resistor. The voltage source equals \(-V_+\). The output resistance \(R_{\text{out}}\) is a function of the ON resistance of the internal MOS switches, the oscillator frequency, and the capacitance and ESR of \(C_1\) and \(C_2\). Since the switching current charging and discharging \(C_1\) is approximately twice as the output current, the effect of the ESR of the pumping capacitor \(C_1\) is multiplied by four in the output resistance. The output capacitor \(C_2\) is charging and discharging at a current approximately equal to the output current, therefore, its ESR only counts once in the output resistance. A good approximation is:

\[
R_{\text{out}} \approx 2R_{\text{SW}} + \frac{2}{f_{\text{osc}} \times C_1} + 4 \text{ESR}_{C_1} + \text{ESR}_{C_2}
\]

(1)

where \(R_{\text{SW}}\) is the sum of the ON resistance of the internal MOS switches shown in the Voltage Inverting Principle.

High value, low ESR capacitors will reduce the output resistance. Instead of increasing the capacitance, the oscillator frequency can be increased to reduce the \(2/(f_{\text{osc}} \times C_1)\) term. Once this term is trivial compared with \(R_{\text{SW}}\) and ESRs, further increasing in oscillator frequency and capacitance will become ineffective.
Typical Applications (continued)

The peak-to-peak output voltage ripple is determined by the oscillator frequency, and the capacitance and ESR of the output capacitor $C_2$:

$$V_{\text{ripple}} = \frac{l_i}{f_{\text{osc}} \times C_2} + 2 \times l_L \times \text{ESR}_C$$

(2)

Again, using a low ESR capacitor will result in lower ripple.

9.2.1.2.1 Paralleling Devices

Any number of LM2662 devices (or LM2663 devices) can be paralleled to reduce the output resistance. Each device must have its own pumping capacitor $C_1$, while only one output capacitor $C_{\text{out}}$ is needed as shown in Figure 18. The composite output resistance is:

$$R_{\text{out}} = \frac{R_{\text{out \ of \ each \ LM2662 \ (or \ LM2663)}}}{\text{Number of Devices}}$$

(3)

![Figure 18. Lowering Output Resistance by Paralleling Devices](image)

9.2.1.2.2 Cascading Devices

Cascading the LM2662 devices (or LM2663 devices) is an easy way to produce a greater negative voltage (as shown in Figure 19). If $n$ is the integer representing the number of devices cascaded, the unloaded output voltage $V_{\text{out}}$ is $(-nV_{\text{in}})$. The effective output resistance is equal to the weighted sum of each individual device:

$$R_{\text{out}} = nR_{\text{out \_1}} + \frac{n}{2}R_{\text{out \_2}} + \ldots + R_{\text{out \_n}}$$

(4)

A three-stage cascade circuit shown in Figure 20 generates $-3$ $V_{\text{in}}$ from $V_{\text{in}}$.

Cascading is also possible when devices are operating in doubling mode. In Figure 21, two devices are cascaded to generate $3$ $V_{\text{in}}$.

An example of using the circuit in Figure 20 or Figure 21 is generating $+15$ V or $-15$ V from a $+5$-V input.

Note that, the number of $n$ is practically limited since the increasing of $n$ significantly reduces the efficiency and increases the output resistance and output voltage ripple.

![Figure 19. Increasing Output Voltage by Cascading Devices](image)
Typical Applications (continued)

Figure 20. Generating $-3\, V_{IN}$ From $+V_{IN}$

Figure 21. Generating $+3\, V_{IN}$ From $+V_{IN}$

9.2.1.2.3 Regulating $V_{OUT}$

It is possible to regulate the output of the LM2662/LM2663 by use of a low dropout regulator (such as LP2986). The whole converter is depicted in Figure 22. This converter can give a regulated output from $-1.5\, V$ to $-5.5\, V$ by choosing the proper resistor ratio:

$$V_{\text{out}} = V_{\text{ref}} \left(1 + \frac{R_f}{100k}\right)$$

where

- $V_{\text{ref}} = 1.23\, V$

The error flag on pin 7 of the LP2986 goes low when the regulated output at pin 5 drops by about 5% below nominal. The LP2986 can be shutdown by taking pin 8 low. The less than 1 $\mu A$ quiescent current in the shutdown mode is favorable for battery powered applications.

Figure 22. Combining LM2662/LM2663 With LP2986 to Make a Negative Adjustable Regulator

Also, as shown in Figure 23 by operating the LM2662/LM2663 in voltage doubling mode and adding a low dropout regulator (such as LP2986) at the output, we can get $+5\, V$ output from an input as low as $+3.3\, V$. 
Typical Applications (continued)

Figure 23. Generating +5 V From +3.3 V Input Voltage

9.2.1.3 Application Curves

Figure 24. Efficiency vs Load Current

Figure 25. Efficiency vs Oscillator Frequency

Figure 26. Output Source Resistance vs Oscillator Frequency
Typical Applications (continued)

9.2.2 Positive Voltage Doubler

9.2.2.1 Design Requirements

The LM2662/LM2663 can operate as a positive voltage doubler (as shown in Figure 27). The doubling function is achieved by reversing some of the connections to the device.

9.2.2.2 Detailed Design Procedure

The input voltage is applied to the GND pin with an allowable voltage from 2.5 V to 5.5 V. The V+ pin is used as the output. The LV pin and OUT pin must be connected to ground. The OSC pin can not be driven by an external clock in this operation mode. The unloaded output voltage is twice of the input voltage and is not reduced by the diode D₁’s forward drop.

The Schottky diode D₁ is only needed for start-up. The internal oscillator circuit uses the V+ pin and the LV pin (connected to ground in the voltage doubler circuit) as its power rails. Voltage across V+ and LV must be larger than 1.5 V to insure the operation of the oscillator. During start-up, D₁ is used to charge up the voltage at V+ pin to start the oscillator; also, it protects the device from turning-on its own parasitic diode and potentially latching-up. Therefore, the Schottky diode D₁ should have enough current carrying capability to charge the output capacitor at start-up, as well as a low forward voltage to prevent the internal parasitic diode from turning-on. A Schottky diode like 1N5817 can be used for most applications. If the input voltage ramp is less than 10 V/ms, a smaller Schottky diode like MBR0520LT1 can be used to reduce the circuit size.

9.2.2.3 Application Curves

See Application Curves section.

9.2.3 Splitting Vᵢᵣ in Half

9.2.3.1 Design Requirements

Another interesting application shown in Figure 28 is using the LM2662/LM2663 as a precision voltage divider. Since the off-voltage across each switch equals Vᵢᵣ/2, the input voltage can be raised to +11 V.
Typical Applications (continued)

9.2.3.2 Detailed Design Procedure

As discussed in the Simple Negative Voltage Converter section, the output resistance and ripple voltage are dependent on the capacitance and ESR values of the external capacitors. The output voltage drop is the load current times the output resistance, and the power efficiency is

\[ \eta = \frac{P_{\text{out}}}{P_{\text{in}}} = \frac{I_L^2 R_L}{I_L^2 R_L + I_L^2 R_{\text{out}} + I_Q(V+)}. \]  

(6)

Where \( I_Q(V+) \) is the quiescent power loss of the IC device, and \( I_L^2 R_{\text{out}} \) is the conversion loss associated with the switch on-resistance, the two external capacitors and their ESRs.

Low ESR capacitors are recommended for both capacitors to maximize efficiency, reduce the output voltage drop and voltage ripple. For convenience, \( C_1 \) and \( C_2 \) are usually chosen to be the same.

The output resistance varies with the oscillator frequency and the capacitors. In Figure 26, the output resistance vs. oscillator frequency curves are drawn for four different capacitor values. At very low frequency range, capacitance plays the most important role in determining the output resistance. Once the frequency is increased to some point (such as 100 kHz for the 47-\( \mu \)F capacitors), the output resistance is dominated by the ON resistance of the internal switches and the ESRs of the external capacitors. A low value, smaller size capacitor usually has a higher ESR compared with a bigger size capacitor of the same type. Ceramic capacitors can be chosen for their lower ESR. As shown in Figure 26, in higher frequency range, the output resistance using the 10-\( \mu \)F ceramic capacitors is close to these using higher value tantalum capacitors.

9.2.3.3 Application Curves

See Application Curves section.
10 Power Supply Recommendations

The LM2662/LM2663 is designed to operate from as an inverter over an input voltage supply range between 1.5 V and 5.5 V when the LV pin is grounded. This input supply must be well regulated and capable to supply the required input current. If the input supply is located far from the LM2662/LM2663 additional bulk capacitance may be required in addition to the ceramic bypass capacitors.

11 Layout

11.1 Layout Guidelines

The high switching frequency and large switching currents of the LM2662/LM2663 make the choice of layout important. The following steps should be used as a reference to ensure the device is stable and maintains proper LED current regulation across its intended operating voltage and current range.

- Place $C_{in}$ on the top layer (same layer as the LM2662/2663) and as close to the device as possible. Connecting the input capacitor through short, wide traces to both the $V+$ and GND pins reduces the inductive voltage spikes that occur during switching which can corrupt the $V+$ line.

- Place $C_{out}$ on the top layer (same layer as the LM2662/2663) and as close as possible to the OUT and GND pin. The returns for both $C_{in}$ and $C_{out}$ should come together at one point, as close to the GND pin as possible. Connecting $C_{out}$ through short, wide traces reduce the series inductance on the OUT and GND pins that can corrupt the $V_{out}$ and GND lines and cause excessive noise in the device and surrounding circuitry.

- Place $C_1$ on the top layer (same layer as the LM2662/2663) and as close to the device as possible. Connect the flying capacitor through short, wide traces to both the $CAP+$ and $CAP-$ pins.

11.2 Layout Example

![Diagram of the LM2662 (LM2663) layout example showing connections between V+, OUT, FC(SD), OSC, LV, CAP+, CAP-, Switch Array, and GND.]
12 Device and Documentation Support

12.1 Device Support

12.1.1 Third-Party Products Disclaimer
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12.2 Related Links
Table 3 lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

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<th>Table 3. Related Links</th>
</tr>
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<tbody>
<tr>
<td><strong>PARTS</strong></td>
</tr>
<tr>
<td>LM2662</td>
</tr>
<tr>
<td>LM2663</td>
</tr>
</tbody>
</table>

12.3 Trademarks
All trademarks are the property of their respective owners.

12.4 Electrostatic Discharge Caution

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.5 Glossary

SLYZ022 — *TI Glossary.*

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.
# Packaging Information

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<th>Package Type</th>
<th>Package Drawing</th>
<th>Pins</th>
<th>Package Qty</th>
<th>Eco Plan (2)</th>
<th>Lead/Ball Finish</th>
<th>MSL Peak Temp (3)</th>
<th>Op Temp (°C)</th>
<th>Device Marking (4/5)</th>
<th>Samples</th>
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<td>Samples</td>
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</table>

(1) The marketing status values are defined as follows:
- **ACTIVE**: Product device recommended for new designs.
- **LIFEBUY**: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
- **NRND**: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
- **PREVIEW**: Device has been announced but is not in production. Samples may or may not be available.
- **OBSOLETE**: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check [http://www.ti.com/productcontent](http://www.ti.com/productcontent) for the latest availability information and additional product content details.
- **TBD**: The Pb-Free/Green conversion plan has not been defined.
- **Pb-Free (RoHS)**: TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.
- **Pb-Free (RoHS Exempt)**: This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.
- **Green (RoHS & no Sb/Br)**: TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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### TAPE AND REEL INFORMATION

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*All dimensions are nominal.*

A0: Dimension designed to accommodate the component width
B0: Dimension designed to accommodate the component length
K0: Dimension designed to accommodate the component thickness
W: Overall width of the carrier tape
P1: Pitch between successive cavity centers
TAPE AND REEL BOX DIMENSIONS

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*All dimensions are nominal*
1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.
NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.
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